

G3VM-□AR/□DR

MOS FET Relays DIP 4-pin, High-current and Low-ON-resistance Type

MOS FET Relays in DIP 4-pin packages that achieve the low ON resistance and high switching capacity of a mechanical relay

- Load voltage: 20 V, 40 V, 60 V, or 100 V
- 20-V Relay: Continuous load current of 3 A max.
- 40-V Relay: Continuous load current of 2.5 A max.
- 60-V Relay: Continuous load current of 2 A max.
- 100-V Relay: Continuous load current of 1 A max.



Note: The actual product is marked differently from the image shown here.

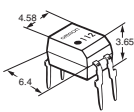
RoHS Compliant

Application Examples

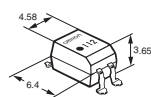
- Communication equipment
- Security equipment
- Power circuit
- Test & Measurement equipment
- Industrial equipment

Package (Unit : mm, Average)

DIP 4-pin
PCB Terminals



Surface-mounting Terminals



Note: The actual product is marked differently from the image shown here.

Model Number Legend

G3VM-□□□□□
 1 2 3 4 5

- 1. Load Voltage**
 2 : 20 V
 4 : 40 V
 6 : 60 V
 10 : 100 V
- 2. Contact form**
 1 : 1a (SPST-NO)
- 3. Package**
 A : DIP 4-pin with PCB terminals
 D : DIP 4-pin with surface-mounting terminals
- 4. Additional functions**
 R : Low ON resistance
- 5. Other informations**
 When specifications overlap, serial code is added in the recorded order.

Ordering Information

Package	Contact form	Load voltage (peak value) *	Continuous load current (peak value) *	Stick packaging			Tape packaging	
				Model		Minimum package quantity	Model	Minimum package quantity
				PCB Terminals	Surface-mounting Terminals			
DIP4	1a (SPST-NO)	20 V	3 A	G3VM-21AR	G3VM-21DR	100 pcs.	G3VM-21DR(TR)	1,500 pcs.
		40 V	2.5 A	G3VM-41AR	G3VM-41DR		G3VM-41DR(TR)	
		60 V	2 A	G3VM-61AR	G3VM-61DR		G3VM-61DR(TR)	
		100 V	1 A	G3VM-101AR	G3VM-101DR		G3VM-101DR(TR)	

* The AC peak and DC value are given for the load voltage and continuous load current.
Note: To order tape packaging for Relays with surface-mounting terminals, add "(TR)" to the end of the model number.

■ Absolute Maximum Ratings (Ta = 25°C)

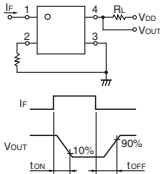
Item	Symbol					Unit	Measurement conditions	
		G3VM-21AR G3VM-21DR	G3VM-41AR G3VM-41DR	G3VM-61AR G3VM-61DR	G3VM-101AR G3VM-101DR			
Input	LED forward current	30				mA		
	Repetitive peak LED forward current	1				A	100 μs pulses, 100 pps	
	LED forward current reduction rate	-0.3				mA/°C	Ta ≥ 25°C	
	LED reverse voltage	5				V		
	Connection temperature	125				°C		
Output	Load voltage (AC peak/DC)	V _{OFF}	20	40	60	100	V	
	Continuous load current (AC peak/DC)	I _o	3	2.5	2	1	A	
	ON current reduction rate	ΔI _o /°C	-30	-25	-20	-10	mA/°C	Ta ≥ 25°C
	Pulse ON current	I _{op}	9	7.5	6	3	A	t=100 ms, Duty=1/10
	Connection temperature	T _J	125				°C	
	Dielectric strength between I/O (See note 1.)	V _{I-O}	2,500				V _{rms}	AC for 1 min
	Ambient operating temperature	T _a	-40 to +85				°C	With no icing or condensation
Ambient storage temperature	T _{stg}	-55 to +125				°C		
Soldering temperature	-	260				°C	10 s	

Note 1: The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■Electrical Characteristics (Ta = 25°C)

Item		Symbol	G3VM-21AR G3VM-21DR	G3VM-41AR G3VM-41DR	G3VM-61AR G3VM-61DR	G3VM-101AR G3VM-101DR	Unit	Measurement conditions		
Input	LED forward voltage	V _F	Minimum				1.18		V	I _F =10 mA
			Typical				1.33			
			Maximum				1.48			
	Reverse current	I _R	Maximum				10		μA	V _R =5 V
	Capacitance between terminals	C _T	Typical				70		pF	V=0, f=1 MHz
Trigger LED forward current	I _{FT} (I _{FC})	Typical	0.7		0.5		mA	I _o =1 A		
			Maximum						3	
	Release LED forward current	I _{FC} (I _{FT})	Minimum				0.1		mA	I _{oFF} =10 μA
Output	Maximum resistance with output ON	R _{ON}	Typical		40	50	80	250	mΩ	G3VM-21AR/21DR/41AR/41DR/61AR/61DR : I _F =5 mA, t < 1 s, I _o =2 A G3VM-101AR/DR : I _F =5 mA, t < 1 s, I _o =1 A
			Maximum		80	150	200	700		
	Current leakage when the relay is open	I _{LEAK}	Maximum				1		μA	V _{OFF} =Load voltage ratings
	Capacitance between terminals	C _{OFF}	Typical				300	250	200	pF
Capacitance between I/O terminals	C _{I-O}	Typical				0.8		pF	f=1 MHz, V _S =0 V	
Insulation resistance between I/O terminals	R _{I-O}	Minimum		1000				MΩ	V _{I-O} =500 VDC, R _{oH} ≤60%	
		Typical		10 ⁸						
Turn-ON time	t _{ON}	Typical		1		0.8		ms	I _F =5 mA, R _L =200 Ω, V _{DD} =20 V (See note 2.)	
		Maximum		5		0.3				
Turn-OFF time	t _{OFF}	Typical		0.3		1		ms	I _F =5 mA, R _L =200 Ω, V _{DD} =20 V (See note 2.)	
		Maximum		1		1				

Note: 2. Turn-ON and Turn-OFF Times



■Recommended Operating Conditions

For usage with high reliability, Recommended Operation Conditions is a measure that takes into account the derating of Absolute Maximum Ratings and Electrical Characteristics.

Each item on this list is an independent condition, so it is not simultaneously satisfy several conditions.

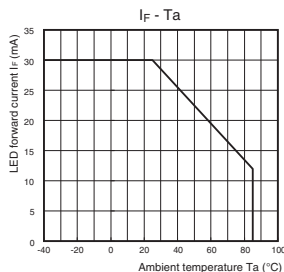
Item	Symbol	G3VM-21AR G3VM-21DR	G3VM-41AR G3VM-41DR	G3VM-61AR G3VM-61DR	G3VM-101AR G3VM-101DR	Unit		
Load voltage (AC peak/DC)	V _{DD}	Maximum				16		V
		Minimum				5		
Operating LED forward current	I _F	Typical				10		mA
		Maximum				25		
		Minimum				5		
Continuous load current (AC peak/DC)	I _o	3	2.5	2	1	A		
Ambient operating temperature	T _a	Minimum				-20		°C
		Maximum				65		

■Spacing and Insulation

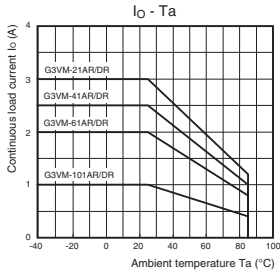
Item	Minimum	Unit
Creepage distances	7.0	mm
Clearance distances	7.0	
Internal isolation thickness	0.4	

Engineering Data

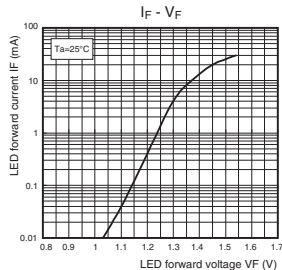
LED forward current vs. Ambient temperature



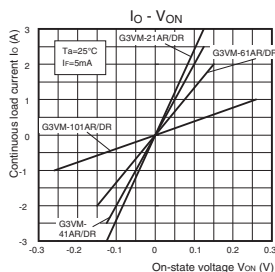
Continuous load current vs. Ambient temperature



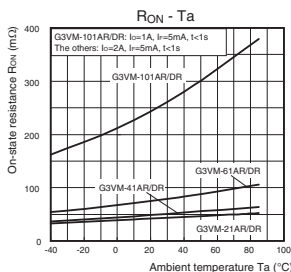
LED forward current vs. LED forward voltage



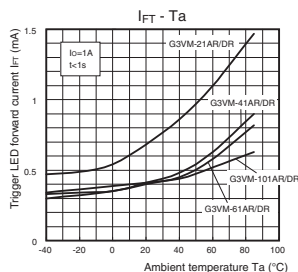
Continuous load current vs. On-state voltage



On-state resistance vs. Ambient temperature

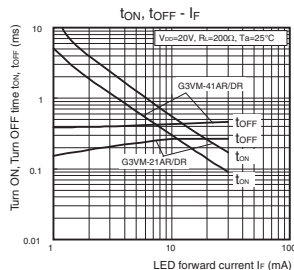


Trigger LED forward current vs. Ambient temperature

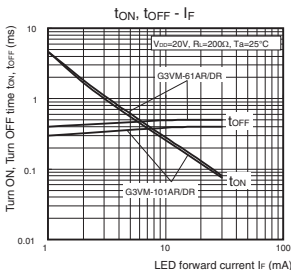


Turn ON, Turn OFF time vs. LED forward current

G3VM-21AR/21DR/41AR/41DR

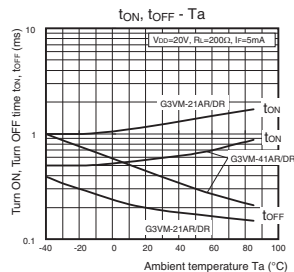


G3VM-61AR/61DR/101AR/101DR

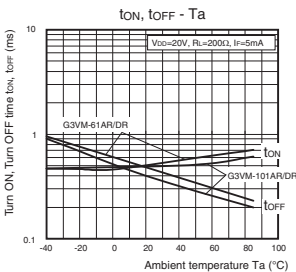


Turn ON, Turn OFF time vs. Ambient temperature

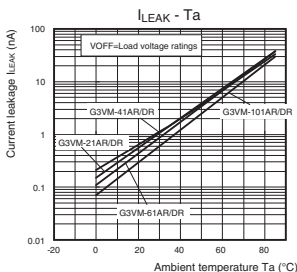
G3VM-21AR/21DR/41AR/41DR



G3VM-61AR/61DR/101AR/101DR



Current leakage vs. Ambient temperature

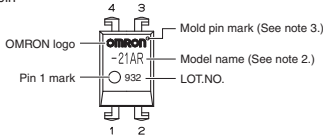


■ Appearance / Terminal Arrangement / Internal Connections

● Appearance

DIP (Dual Inline Package)

DIP 4-pin

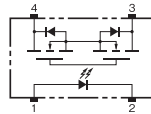


Note: 1. The actual product is marked differently from the image shown here.

Note: 2. "G3VM" does not appear in the model number on the Relay.

Note: 3. The indentation in the corner diagonally opposite from the pin 1 mark is from a pin on the mold.

● Terminal Arrangement/Internal Connections (Top View)

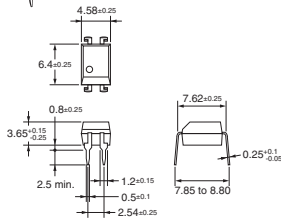


■ Dimensions (Unit: mm)



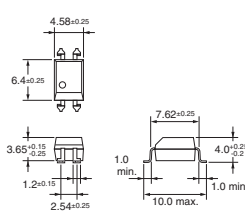
PCB Terminals

Weight: 0.25 g

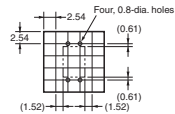


Surface-mounting Terminals

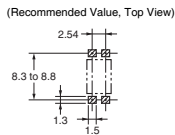
Weight: 0.25 g



PCB Dimensions (BOTTOM VIEW)



Actual Mounting Pad Dimensions (Recommended Value, Top View)



Note: The actual product is marked differently from the image shown here.

■ Approved Standards

UL recognized

Approved Standards	Contact form	File No.
UL (recognized)	1a (SPST-NO)	E80555

■ Safety Precautions

- Refer to the *Common Precautions for All MOS FET Relays* for precautions that apply to all MOS FET Relays.

Introduction
General-purpose
High-voltage
Multi-contact pair
Low-ohmic-resistance
High-current and
High-ohmic-resistance
Small and High-
High-dielectric-
High-straight
Current-limiting
Low-ohmic-resistance
Small and High-
Certified Models with
Standard Certification
DIP
SOP
SSOP
USOP
VSON
G3VM-□AR/□DR